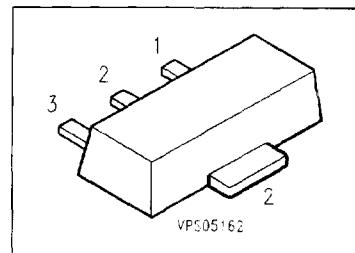


Silicon Switching Diodes

BAW 79 A
... **BAW 79 D**

- For high-speed switching
- High breakdown voltage
- Common cathode



Type	Marking	Ordering Code (tape and reel)	Pin Configuration	Package ¹⁾
BAW 79 A	GE	Q62702-A781		
BAW 79 B	GF	Q62702-A782		
BAW 79 C	GG	Q62702-A771		
BAW 79 D	GH	Q62702-A733	 EHA07003	SOT-89

Maximum Ratings per Diode

Parameter	Symbol	Values				Unit
		BAW 79 A	BAW 79 B	BAW 79 C	BAW 79 D	
Reverse voltage	V_R	50	100	200	400	V
Peak reverse voltage	V_{RM}	50	100	200	400	
Forward current	I_F			1		A
Peak forward current	I_{FM}			1		
Surge forward current $t = 1 \mu\text{s}$	I_{FS}			10		
Total power dissipation $T_s = 115^\circ\text{C}$	P_{tot}			1		W
Junction temperature	T_j			150		$^\circ\text{C}$
Storage temperature range	T_{stg}			$-65 \dots +150$		

Thermal Resistance

Junction - ambient ²⁾	$R_{th JA}$	≤ 175	K/W
Junction - soldering point	$R_{th JS}$	≤ 35	

¹⁾ For detailed information see chapter Package Outlines.

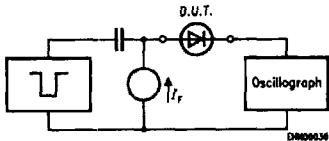
²⁾ Package mounted on epoxy pcb 40 mm \times 40 mm \times 1.5 mm/6 cm² Cu.

Electrical Characteristics per Diode
at $T_A = 25^\circ\text{C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC characteristics					
Breakdown voltage $I_{(BR)} = 100 \mu\text{A}$	$V_{(BR)}$				V
BAW 79 A		50	—	—	
BAW 79 B		100	—	—	
BAW 79 C		200	—	—	
BAW 79 D		400	—	—	
Forward voltage ¹⁾ $I_F = 1 \text{ A}$ $I_F = 2 \text{ A}$	V_F			1.6 2	V
Reverse current $V_R = V_{R\text{max}}$ $V_R = V_{R\text{max}}, T_A = 150^\circ\text{C}$	I_R			1 50	μA

AC characteristics

Diode capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	C_D	—	10	—	pF
Reverse recovery time $I_F = 200 \text{ mA}, I_R = 200 \text{ mA},$ $R_L = 100 \Omega$ measured at $I_R = 20 \text{ mA}$	t_{rr}	—	1	—	μs

Test circuit for reverse recovery time

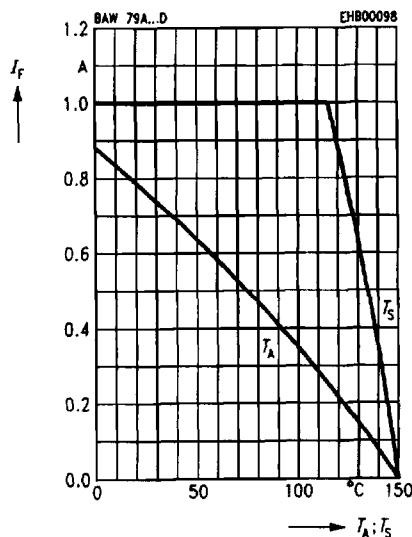
Pulse generator: $t_p = 5 \mu\text{s}, D = 0.05$
 $t_r = 0.6 \text{ ns}, R_j = 50 \Omega$

Oscilloscope: $R = 50 \Omega$
 $t_r = 0.35 \text{ ns}$
 $C \leq 1 \text{ pF}$

¹⁾ Pulse test: $t_p \leq 300 \mu\text{s}, D = 2 \%$.

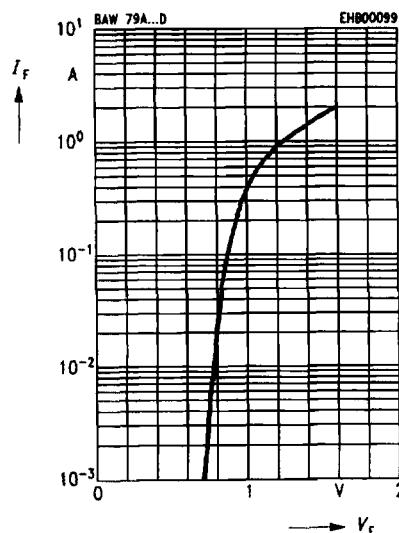
Forward current $I_F = f(T_A^*, T_S)$

* Package mounted on epoxy



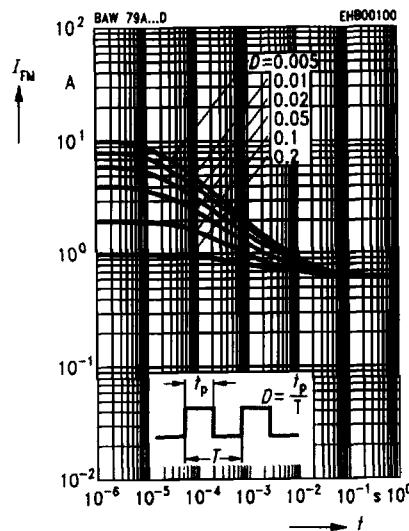
Forward current $I_F = f(V_F)$

$T_A = 25^\circ\text{C}$



Peak forward current $I_{FM} = f(t)$

$T_A = 25^\circ\text{C}$



Reverse current $I_R = f(T_A)$

$V_R = V_{Rmax}$

